Attorney's Doo	sket No	
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## **Combined Declaration and Power of Attorney**

As a below na	amed inventor,	hereby declare that	·		
This declarati	on is of the follo	owing type:			
[X] origir	nal [ ] suppl	emental			
, .	nal stage of PC ional [	T ] continuation	[ ] continua	ation-in-part	
My residence	, post office add	dress and citizenship	are as stated	next to my name,	
inventor (if plu		listed below) of the s		me is listed below) or an origi which is claimed and for whic	
Semiconduc	tor Device and	Method for Manuf	acturing the	Same	
the specificati	ion of which		•		
[X]	is attached he	reto.			
[1]	as United		Serial Number	(if applicab	
[X]		September 24  nternational Applicational Application		PCT/JP2004/013965	_ and, (if applicable).
	that I have revi		nd the contents	s of the above-identified spec	
l acknowledge	-	close information wi		I to patentability as defined in	Title 37, Code of
application(s) at least one c box, any forei	for patent or in ountry other tha gn application f	ventor's certificate, on the United States,	or 365(a) of an listed below a 's certificate, c	e, Section 119(a)-(d) or 365(ly PCT International application and have also identified below or PCT International application	on which designated y, by checking the
	PRIOR FORE	IGN APPLICATION	S, BENEFIT C	LAIMED UNDER 35 USC §1	19(a)
Application	n Number	Country		Date of Filing (Day/Month/Year)	Priority Claimed Under 35 USC 119
P2003-	333690	Japar	1	25 / September / 200	
					Tyes No
					Yes   No

I hereby claim the benefit under Title 35, United States Code, Section 119(e) of any United States provisional application(s) listed below.

## PRIOR U.S. PROVISIONAL APPLICATIONS, BENEFIT CLAIMED UNDER 35 USC §119(e) **Application Number** Filing Date

I hereby claim the benefit of Title 35, United States Code Section 120 of any United States application(s), or 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code Section 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application:

> PRIOR U.S. APPLICATIONS OR PCT INTERNATIONAL APPLICATIONS DESIGNATING THE U.S., BENEFIT CLAIMED UNDER 35 USC §120

(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the registered practitioners of Drinker Biddle & Reath LLP included in the Customer Number provided below to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

Customer Number 55694

Send Correspondence to:

Customer Number 55694

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